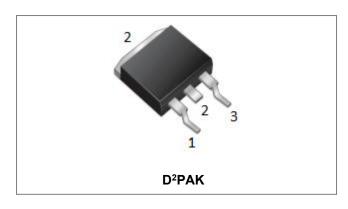


MBRB2060CT

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MBRB2060CT SCHOTTKY RECTIFIER



Features

- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Circuit Diagram

Base common Cathode

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|--|-------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 60 | V |
| Average Rectified Forward Current (Per Device) | IF (AV) | 50% duty cycle @Tc=80°C, rectangular wave form | 10(Per Leg) 20(Per Device) | A |
| RMS Forward Current | I _{F(RMS)} | - | 22.2 | A |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | IFSM | 8.3ms, Half Sine pulse | 150 | А |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|-------------------------------|-----------------|--|------|--------|-------|
| Forward Voltage Drop | V _{F1} | @ 10A, Pulse, T _J = 25 °C | 0.74 | 0.80 | V |
| (Per Leg) * | V _{F2} | @ 10A, Pulse, T _J = 125 °C | 0.63 | 0.70 | V |
| Reverse Current (Per Leg) * | I _{R1} | $@V_R = rated V_{R,} T_J = 25 \circ C$ | 0.02 | 1 | mA |
| | I _{R2} | @V _R = rated V _R , T _J = 125 °C | 9 | 50 | mA |
| Junction Capacitance(Per Leg) | Ст | $@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C, f_{SIG} = 1MHz$ | 180 | 400 | pF |
| Series Inductance(Per Leg) | Ls | Measured lead to lead 5 mm from package body | 8.0 | - | nH |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |

Pulse width < 300 μ s, duty cycle < 2%

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Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|--|--------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case(Per Leg) | R _{θJC} | DC operation | 2.3 | °C/W |
| Approximate Weight | wt | - | 1.85 | g |
| Case Style | D ² PAK | | | |

Ratings and Characteristics Curves

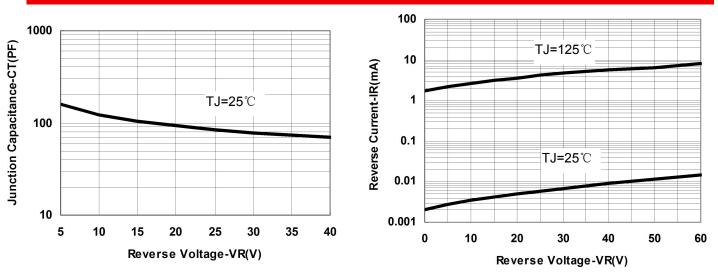


Fig.1-Typical Junction Capacitance



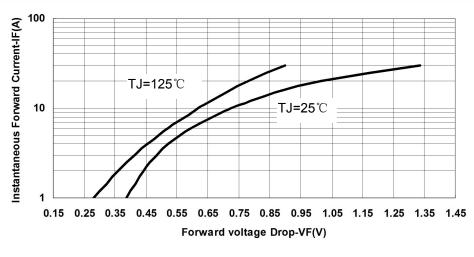


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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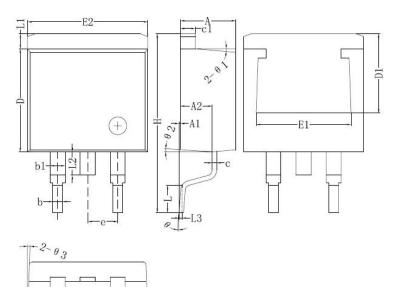


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RoHS

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Mechanical Dimensions D²PAK



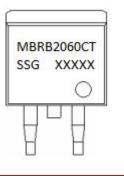
| Symbol | Dimensions in millimeter | | | |
|--------|--------------------------|---------|-------|--|
| | Min. | Typical | Max. | |
| A | 4.47 | 4.70 | 4.85 | |
| A1 | 0 | 0.10 | 0.25 | |
| A2 | 2.59 | 2.69 | 2.89 | |
| b | 0.71 | 0.81 | 0.96 | |
| b1 | 1.17 | 1.27 | 1.37 | |
| С | 0.31 | 0.38 | 0.61 | |
| c1 | 1.17 | 1.27 | 1.37 | |
| D | 8.50 | 8.70 | 8.90 | |
| D1 | 6.40 | | | |
| E | 10.01 | 10.16 | 10.31 | |
| E1 | 7.6 | | | |
| E2 | 9.98 | 10.08 | 10.31 | |
| е | | 2.54 | | |
| Н | 14.6 | 15.1 | 15.6 | |
| L | 2.00 | 2.30 | 2.74 | |
| L1 | 1.12 | 1.27 | 1.42 | |
| L2 | 1.30 | | 2.20 | |
| L3 | | 0.25BSC | | |
| е | 0 | - | 8° | |
| e1 | | 5° | | |
| e2 | | 4° | | |
| e3 | | 4° | | |

Ordering Information

| Device | Package | Shipping |
|------------|--------------------|---------------|
| MBRB2060CT | D ² PAK | 800pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

В 20

60

CT SSG

YY WW

L

MBR = Device Type

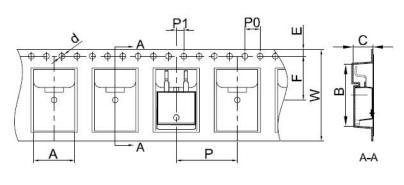
- = Device Type = Package type = Forward Current (20A) = Reverse Voltage(60V)

= Configuration = SSG

- = Year
- = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



| SYMBOL | Millimeters | | |
|----------|-------------|-------|--|
| STIVIDUL | Min. | Max. | |
| A | 10.70 | 10.90 | |
| В | 16.03 | 16.23 | |
| С | 5.11 | 5.31 | |
| d | 1.45 | 1.65 | |
| E | 1.65 | 1.85 | |
| F | 11.40 | 11.60 | |
| P0 | 3.90 | 4.10 | |
| Р | 15.90 | 16.10 | |
| P1 | 1.90 | 2.10 | |
| W | 23.90 | 24.30 | |

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